

EV1906-S-00A

80V, High Frequency Half-Bridge Gate Driver EV Board

DESCRIPTION

This is EV board documentation for MP1906. The MP1906 is a high-performance, 80V, gate driver that can drive two external N-MOSFETs in a half-bridge configuration with 12V gate supply. It accepts independent gate input signals and provides shoot-through prevention. During voltage lockout, the output of the high-and low-side driver goes low to prevent erratic operation under low supply conditions. The high-current driving capability and short dead time make it suitable for high-power and high-efficiency power applications.

This demo board is configured to a Half-Bridge.. For simplicity, HPWM and LPWM are connected together and drove by a same PWM signal generated by NE555. The user can evaluate MP1906 performance expediently..

ELECTRICAL SPECIFICATION

| Parameter | Symbol | Value | Units |
|---------------------|-----------------|---------|-------|
| Driver Voltage | V_{DD} | 10 – 16 | V |
| Input Power Voltage | V_{POWER} | 0-80 | V |
| Duty | D | 50 | % |
| Frequency | F _{sw} | 200 | kHz |

FEATURES

- Drives Two Low Cost and High-Efficiency N-MOSFETs
- 10V-16V Gate Drive Supply
- 3.3V, 5V Logic Compatibility
- 80ns Propagation Delay Time
- Less than 90µA Quiescent Current
- Undervoltage Lockout for Both Channels
- Input Signal Overlap Protection
- Internal 150ns Dead Time
- Available in a Compact 8-pin SOIC Package

APPLICATIONS

- Motor Drivers
- Half-Bridge Power Supplies
- Avionics DC-DC converters
- Active-clamp Forward Converters

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page. "MPS" and "The Future of Analog IC Technology" are registered trademarks of Monolithic Power Systems, Inc.

EV1906-S-00A EVALUATION BOARD

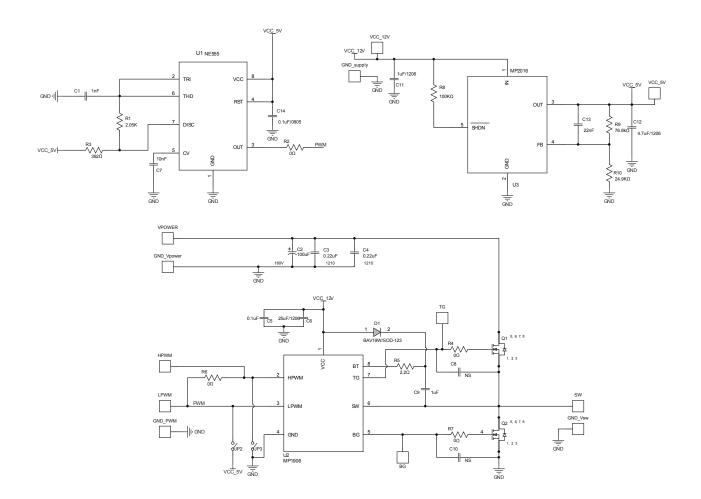


(L x W x H) 6.4cm x 6.4cm x 2.5cm

| Board Number | MPS IC Number |
|--------------|---------------|
| EV1906-S-00A | MP1906DS |



EVALUATION BOARD SCHEMATIC





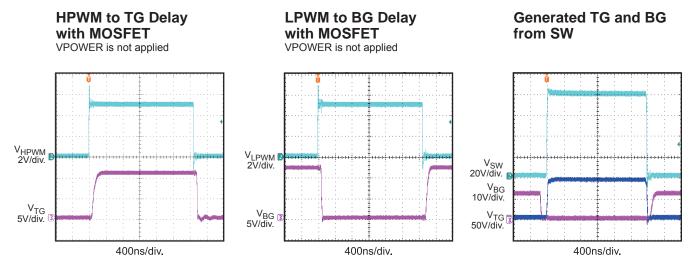
EV1906-S-00A BILL OF MATERIALS

| Qty | RefDes | Value | Description | Package | Manufacturer | Manufacturer P/N |
|-----|-----------------|----------|--|---------------|---------------------|--------------------|
| 1 | C1 | 1nF | Ceramic Cap,16V,X7R | 0603 | muRata | GRM188R71C102KA01D |
| 1 | C2 | 100µF | 100V, Aluminium Cap | 10X22X5 mm | 红宝石 | CD11-100V-100µF |
| 2 | C3,C4 | 0.22μF | Ceramic Cap., 250V, X7R | 1210 | muRata | GRM32DR72E224KW01D |
| 2 | C5,C14 | 0.1μF | Ceramic Cap., 16V, X7R | 0805 | muRata | GRM219R71C104KA01D |
| 1 | C6 | 22µF | Ceramic Cap,25V,X7R | 1206 | muRata | GRM31ER71E226KE15L |
| 1 | C7 | 10nF | Ceramic Cap,16V,X7R | 0603 | muRata | GRM188R71C103KA01D |
| 2 | C8,C10 | NS | | 0603 | | |
| 1 | C9 | 1µF | Ceramic Cap, 25V, X5R | 0805 | muRata | GRM216R61E105KA12D |
| 1 | C11 | 1µF | Ceramic Cap, 25V, X7R | 1206 | muRata | GRM31MR71E105KC01L |
| 1 | C12 | 4.7μF | Ceramic Cap, 25V, X7R | 1206 | muRata | GRM31CR71E475KA88L |
| 1 | C13 | 22nF | Ceramic Cap,16V,X7R | 0603 | muRata | GRM188R71C223KA01D |
| 1 | R1 | 2.05k | Thick Film Res, 1% | 0603 | ROYAL | RL0603FR-072K05L |
| 2 | R3 | 392Ω | Thick Film Res, 1% | 0603 | ROYAL | RL0603FR-07392RL |
| 4 | R2,R4, R6,R7 | 0Ω | Thick Film Res., 1% | 0603 | Yageo | RC0603FR-070RL |
| 1 | R5 | 2.2Ω | Thick Film Res., 1% | 0603 | ROYAL | RL0603FR-072R2L |
| 1 | R8 | 100k | Thick Film Res., 1% | 0603 | ROYAL | RL0603FR-07100KL |
| 1 | R9 | 76.8k | Thick Film Res., 1% | 0603 | ROYAL | RC0603FR-0776K8L |
| 1 | R10 | 24.9k | Thick Film Res., 1% | 0603 | ROYAL | RL0603FR-0724K9L |
| 1 | D1 | BAV19W | Switching diodes | SOD-123 | DIODES | BAV19W-7-F |
| 2 | Q1,Q2 | Si4100DY | N-channel MOSFET | SO8 | VISHAY | Si4100DY |
| 1 | U1 | NE555 | General Purpose Single Bipolar Timers | SOIC8 | STMicroelectro nics | NE555D |
| 1 | U2 | MP1906 | 80V Half Bridge Driver | SOIC8 | MPS | MP1906R2 |
| 1 | U3 | MP2016 | LDO, 5V, 30mA | TSOT23-5 | MPS | MP2016D |



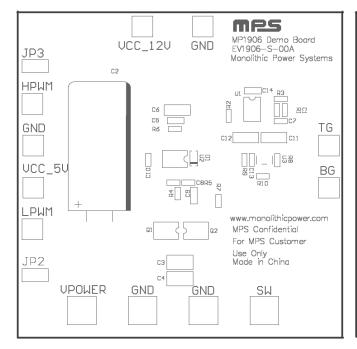
EVB TEST RESULTS

Performance waveforms are tested on the evaluation board. $V_{POWER} = 80V$, $V_{DD} = 12V$, Duty=50%, Frequency=200kHz, $T_A = 25^{\circ}$ C, unless otherwise noted.





PRINTED CIRCUIT BOARD LAYOUT



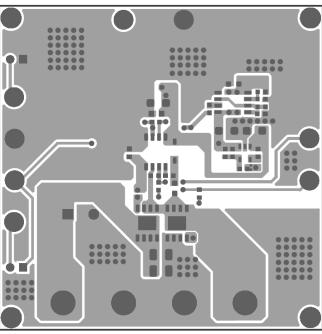


Figure 1—Top Silk Layer

Figure 2—Top Layer

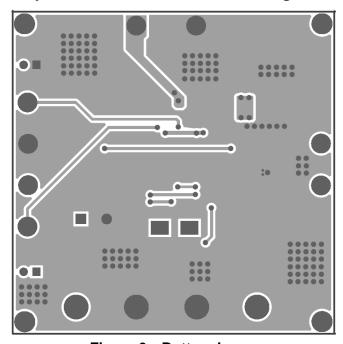


Figure 3—Bottom Layer



QUICK START GUIDE

EV1906-S-00A is configured in a half-bridge. Below is the recommended setting for users to evaluate the EV board.

- 1. Preset Driver Power Supply between 10V-16V.
- 2. Preset Input Power Supply between 0V-80V.
- 3. Connect Driver Power Supply terminals to:
 - a. Positive (+): VCC_12V
 - b. Negative (-): GND
- 4. Connect Input Power Supply terminals to:
 - a. Positive (+): VPOWER
 - b. Negative (-): GND
- 5. Connect Load to:
 - a. Positive (+): SW
 - b. Negative (-): GND
- 6. Turn on Driver Power Supply.
- 7. To turn off the board, please follow these steps:
 - a. Turn off load.
 - b. Turn off Input Power Supply.
 - c. Turn off Driver Power Supply.

NOTICE: The information in this document is subject to change without notice. Please contact MPS for current specifications. Users should warrant and guarantee that third party Intellectual Property rights are not infringed upon when integrating MPS products into any application. MPS will not assume any legal responsibility for any said applications.